

TECHNICAL DATA  
DATA SHEET 632, REV. A

**HERMETIC POWER SCHOTTKY RECTIFIER**  
**Low Reverse Leakage**  
**175 °C Operating Temperature**

**DESCRIPTION:** 60 VOLT, 15 AMP, POWER SCHOTTKY RECTIFIER IN A SHD-1/1B PACKAGE.

**MAXIMUM RATINGS**

ALL RATINGS ARE @  $T_c = 25\text{ }^\circ\text{C}$  UNLESS OTHERWISE SPECIFIED.

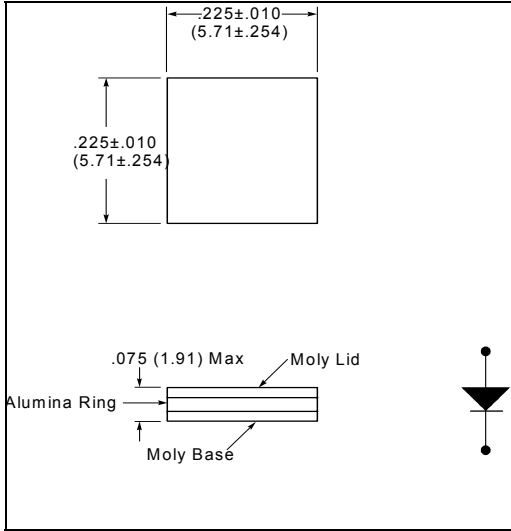
RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	60	Volts
MAXIMUM DC OUTPUT CURRENT (With Cathode Maintained @ $T_c=100\text{ }^\circ\text{C}$ )	$I_o$	15	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT ( $t=8.3\text{ms}$ , Sine)	$I_{FSM}$	280	Amps
MAXIMUM JUNCTION CAPACITANCE ( $V_r=5\text{V}$ )	$C_T$	720	pF
MAXIMUM THERMAL RESISTANCE (Junction to Mounting Surface, Cathode)	$R_{\theta JC}$	0.85	$^\circ\text{C/W}$
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE	Top/Tstg	-65 to + 175	$^\circ\text{C}$

**ELECTRICAL CHARACTERISTICS**

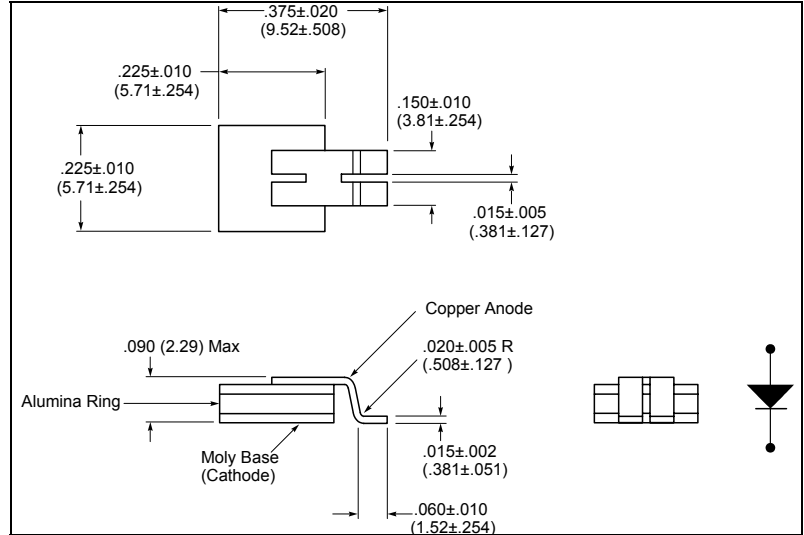
CHARACTERISTIC			
MAXIMUM FORWARD VOLTAGE DROP, Pulsed ( $I_f = 15\text{ Amps}$ ) $T_J = 25\text{ }^\circ\text{C}$ $T_J = 125\text{ }^\circ\text{C}$	$V_f$	.64 .57	Volts
MAXIMUM REVERSE CURRENT ( $I_r$ @ 60V PIV) $T_J = 25\text{ }^\circ\text{C}$ $T_J = 125\text{ }^\circ\text{C}$	$I_r$	.40 30	mA

**SENSITRON**  
**DATA SHEET 632, REV. A**

**MECHANICAL DIMENSIONS: In Inches / mm**

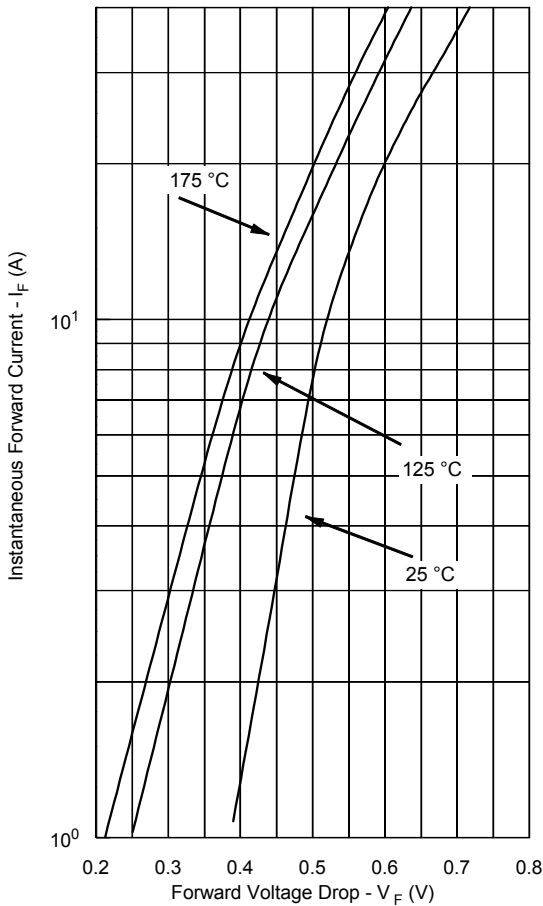


**SHD-1**

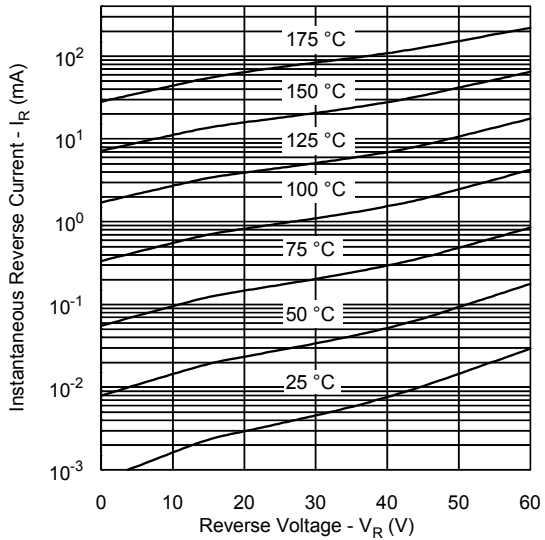


**SHD-1B**

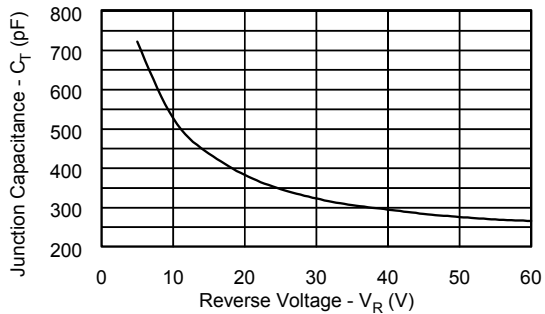
**Typical Forward Characteristics**



**Typical Reverse Characteristics**



**Typical Junction Capacitance**



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